

	<h2 style="color: red;">NTD3813NT4G</h2>
	<p>Hersteller-Teilenummer: NTD3813NT4G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 16V 9.6A DPAK</p> <hr/> <p>Datenblätter:  NTD3813NT4G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 10109 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD3813NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 16V 9.6A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10109 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.2W (Ta), 34.9W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	16V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9.6A (Ta), 51A (Tc)
Rds On (Max) @ Id, Vgs	8.75 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12.8nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	963pF @ 12V
Verpackung	Tape & Reel (TR)



















































NTD3813NT4G ist neu im Original, Suche NTD3813NT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD3813NT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD3813NT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD3808NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A DPAK</p>	 <p>NTD3817N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 7.6A IPAK</p>	 <p>NTD3813N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 9.6A IPAK</p>	 <p>NTD3808N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>
 <p>NTD3808N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>	 <p>NTD3817N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 7.6A IPAK</p>	 <p>NTD3817NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 7.6A DPAK</p>	 <p>NTD3813N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 9.6A IPAK</p>

heiße Teile

Mehr

 NTD3055L104G	 NTD3055L104T4G	 NTD3055L170	 NTD3055L170-001	 NTD3055L170-1G
 NTD3055L170G	 NTD3055L170T4	 NTD3055L170T4G	 NTD3055LT4G	 NTD3055VLT4G
 NTD30N02G	 NTD30N02T4	 NTD30N02T4G	 NTD30N06RT4	 NTD30N06T4G
 NTD32N06-001	 NTD32N06-1G	 NTD32N06G	 NTD32N06L	 NTD32N06L-001
 NTD32N06L-1G	 NTD32N06LG	 NTD32N06LT4G	 NTD32N06T4G	 NTD3808NT4G
 NTD3817NT4G	 NTD40N03R	 NTD40N03R-1	 NTD40N03R-1G	 NTD40N03RG
 NTD40N03RT4	 NTD40N03RT4G	 NTD4302-001	 NTD4302-001G	 NTD4302-1G
 NTD4302G	 NTD4302T4	 NTD4302T4G	 NTD4804N	 NTD4804NT4G
 NTD4805N	 NTD4805N-1G	 NTD4805NT4G	 NTD4806N	 NTD4806N-35G
 NTD4806NA-35G	 NTD4806NG	 NTD4806NT4G	 NTD4808N	 NTD4808N-35G

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